

DOCKET NO: 243712US2S DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :  
RIICHIRO SHIROTA, ET AL. : ATTN: APPLICATION DIVISION  
SERIAL NO: NEW U.S. APPLN. :  
FILED: HERewith :  
FOR: FLASH MEMORY HAVING :  
MEMORY SECTION AND :  
PERIPHERAL CIRCUIT SECTION :  
AND MANUFACTURING THE :  
SAME :

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to a first examination on the merits, please amend the above-identified application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 3 of this paper.

**Remarks/Arguments** begin on page 8 of this paper.